

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7PAU04FU

Dual Inverter (unbuffer) with 3.6 V Tolerant Input

#### **Features**

- Low voltage operation:  $V_{CC} = 1.8 \sim 3.6 \text{ V}$
- Quiescent supply current:  $I_{CC} < 20 \mu A \text{ (max)}$

$$V_{CC} = 3.6 \text{ V}, \text{ Ta} = -40 \sim 85^{\circ}\text{C}$$

• High-speed operation:  $t_{pd} = 3.5 \text{ ns (max) (V}_{CC} = 3.0 \sim 3.6 \text{ V)}$ 

 $t_{pd} = 4.2 \text{ ns (max)} (V_{CC} = 2.3 \sim 2.7 \text{ V})$ 

 $t_{pd} = 8.4 \text{ ns (max) (VCC} = 1.8 \text{ V)}$ 

• High-output current: I<sub>OH</sub>/I<sub>OL</sub> = ±24 mA (min) (V<sub>CC</sub> = 3.0 V)

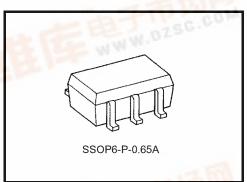
 $I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$ 

 $IOH/IOL = \pm 6 \text{ mA (min) (VCC} = 1.8 \text{ V)}$ 

- Latch-up performance: ±300 mA
- ESD Performance: ±200 V (JEITA)

±2000 V (MIL)

• 3.6 V tolerant function for input and power down protection are provided.



Weight: 0.0068 g (typ.)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	-0.5~4.6	V
DC input voltage	V <sub>IN</sub>	-0.5~4.6	V
DC output voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5(Note 1)	V
Input diode current	I <sub>IK</sub>	-50	mA
Output diode current	lok	±50 (Note 2)	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±100	mA
Power dissipation	PD	200	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

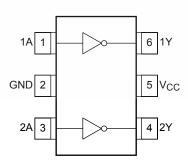
Note 1: Date retention only

Note 2: High or low state. VOUT absolute maximum rating must be observed.

#### Marking

# E A 6

## Pin Assignment (top view)



# Logic Diagram



## **Truth Table**

А	Y
L	Н
Н	L

# **Operating Ranges**

Characteristics	Symbol	Rating	Unit	
Supply voltage	Vac	1.8~3.6	V	
Supply voltage	V <sub>CC</sub>	1.2~3.6 (Note 3)	V	
Input voltage	V <sub>IN</sub>	-0.3~3.6	V	
Output voltage	V <sub>OUT</sub>	0~V <sub>CC</sub> (Note 4)	V	
	I <sub>OH</sub> /I <sub>OL</sub>	±24 (Note 5)		
Output Current		±18 (Note 6)	mA	
		±6 (Note 7)		
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note 8)	ns/V	

Note 3: Date Retention Only

Note 4: High or low state

Note 5: V<sub>CC</sub> = 3.0~3.6 V

Note 6:  $V_{CC} = 2.3 \sim 2.7 \text{ V}$ 

Note 7:  $V_{CC} = 1.8 \text{ V}$ 

Note 8:  $V_{CC} = 3.0 \text{ V}$ 



# **Electrical Characteristics**

# DC Characteristics ( $Ta = -40 \sim 85$ °C)

Characteristics		Symbol Test Condition			Min	Max	Unit										
Charac	teristics	Symbol	Test Condition		V <sub>CC</sub> (V)	IVIII	IVIAX	Offic									
"H" level		Viii			1.8	0.85 × V <sub>CC</sub>	-										
		V <sub>IH</sub> —		2.3~3.6	0.8 × V <sub>CC</sub>	_	V										
Input voltage	"L" level	VIL			1.8	_	0.15 × V <sub>CC</sub>	V									
	L level	VIL		_	2.3~3.6	_	0.2 × V <sub>CC</sub>										
				I <sub>OH</sub> = -100 μA	1.8~3.6	V <sub>CC</sub> - 0.2											
				$I_{OH} = -6 \text{ mA}$	1.8	1.4											
				$I_{OH} = -12 \text{ mA}$	2.3	1.8											
	"H" level	V <sub>OH</sub>	$V_{IN} = V_{IL}$	$I_{OH} = -18 \text{ mA}$	2.3	1.7											
				$I_{OH} = -12 \text{ mA}$	2.7	2.2											
										İ			$I_{OH} = -18 \text{ mA}$	3.0	2.4		
Output voltage										$I_{OH} = -24 \text{ mA}$	3.0	2.2		V			
			I <sub>OL</sub> = 1	$I_{OL} = 100 \mu A$	1.8~3.6	_	0.2										
								ı		I <sub>OH</sub> = 6 mA	I <sub>OH</sub> = 6 mA	1.8		0.3	] <b> </b>		
					I <sub>OL</sub> = 12 mA	2.3	_	0.4									
	"L" level	V <sub>OL</sub>	$V_{IN} = V_{IH}$	I <sub>OL</sub> = 18 mA	2.3	_	0.6										
				I <sub>OL</sub> = 12 mA	2.7	_	0.4										
			I <sub>OL</sub> = 18 mA	3.0	_	0.4											
				I <sub>OL</sub> = 24 mA	3.0	_	0.55										
Input leakage curre	ent	I <sub>IN</sub>	V <sub>IN</sub> = 0~3.6 V		2.7~3.6	_	±5.0	μА									
Quiggoont gunsly s	urrant	laa	V <sub>IN</sub> = V <sub>CC</sub> or GN	ID	2.7~3.6	_	20.0	^									
Quiescent supply c	Quiescent supply current I <sub>C</sub>		$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		2.7~3.6	_	±20.0	μΑ									

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# **TOSHIBA**

## AC Characteristics (Ta = $-40 \sim 85$ °C, input $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500$ $\Omega$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub>	(Fig.1, 2)	1.8	1.0	8.4	
			$2.5\pm0.2$	0.8	4.2	ns
	<sup>t</sup> pHL		$3.3 \pm 0.3$	0.6	3.5	

For  $C_L = pF$ , add approximately 300 ps to the Ac maximum specification.

## Dynamic Switching Characteristics (Ta = 25°C, input $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	1	Тур.	Unit
Characteristics	Gymbol	rest conducti	V <sub>CC</sub> (V)	τyp.	Onit
		$V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9)	1.8	0.25	
Quiet output maximum dynamic $V_{\mbox{OL}}$	$V_{OLP}$	$V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9)	2.5	0.6	ns
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9)	3.3	0.8	
	V <sub>OLV</sub>	$V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9)	1.8	-0.25	
Quiet output maximum dynamic VOL		$V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9)	2.5	-0.6	ns
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9)	3.3	-0.8	
Quiet output maximum dynamic VOH		$V_{IN} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9)	1.8	1.5	
		$V_{IN} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9)	2.5	1.9	ns
		$V_{IN} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 9)	3.3	2.2	

Note 9: Parameter guaranteed by design.

### **Capacitive Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition			Тур.	Unit
	-,			V <sub>CC</sub> (V)	. , p.	2
Input capacitance	C <sub>IN</sub>	_	_	1.8, 2.5, 3.3	4	pF
Power dissipation capacitance	C <sub>PD</sub>	$f_{\text{IN}} = 10 \text{ MHz}$	(Note 10)	1.8, 2.5, 3.3	7	pF

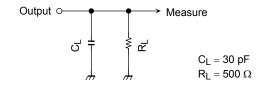
Note 10: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ 

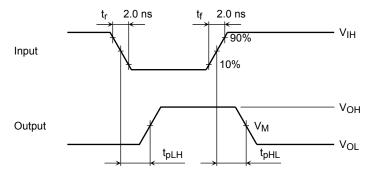
# **Test Circuit**

# Figure 1



## **AC Waveform**

# Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>



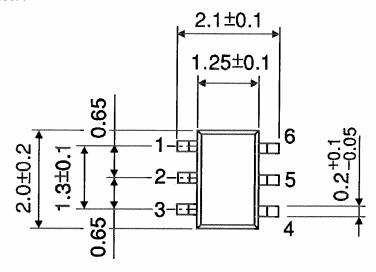
Symbol	V <sub>CC</sub>						
Symbol	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2~\textrm{V}$	1.8 V				
$V_{IH}$	2.7 V	V <sub>CC</sub>	V <sub>CC</sub>				
V <sub>M</sub>	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2				

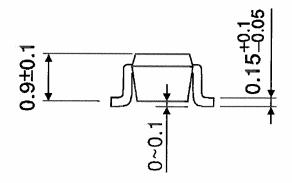
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# **Package Dimensions**

SSOP6-P-0.65A

Unit: mm





Weight: 0.0068 g (typ.)

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20070701-EN GENERAL

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